L Number	Hits	Search Text	DB	Time stamp
-	705	438/30.ccls.	USPAT; US-PGPUB	2004/10/06 18:11
-	938	438/151.ccls. not (438/30.ccls.)	USPAT; US-PGPUB	2004/10/06 18:51
-	314	438/158.ccls. not (438/151.ccls. 438/30.ccls.)	USPAT; US-PGPUB	2004/10/06 19:54
-	66	438/609.ccls. not (438/158.ccls. 438/151.ccls. 438/30.ccls.)	USPAT; US-PGPUB	2004/10/06 19:54
-	195	((thin adj film adj transistor$1) TFT) and (single near etch$7)	USPAT; US-PGPUB	2004/10/12 14:57
-	17	(((thin adj film adj transistor$1) TFT) and (single near etch$7)) and ((single near etch$7) with (source drain))	USPAT; US-PGPUB	2004/10/12 14:32
-	11	"5874326"	USPAT; US-PGPUB	2004/10/12 14:40
-	1	"5874326"	DERWENT	2004/10/12 14:40
-	20	(U11-C18A1 and U13-D07 and U14-H01A and U14-K01A2B).epi.	DERWENT	2004/10/12 14:56
-	1	(L03-C03 and L03-G05A and L04-C07 and L04-E01).cpi.	DERWENT	2004/10/12 14:56
-	313	((thin adj film adj transistor$1) TFT) and ((reduc$5 near mask$5))	USPAT; US-PGPUB	2004/10/12 14:58
-	52	(((thin adj film adj transistor$1) TFT) and ((reduc$5 near mask$5))) and (bottom near gate)	USPAT; US-PGPUB	2004/10/12 17:42
-	2	(bottom adj gate) and ((single near etch$5) with (source drain))	USPAT; US-PGPUB	2004/10/12 15:33
-	15	((thin adj film adj transistor$1) TFT) and (photo$1etching$1process)	USPAT; US-PGPUB	2004/10/12 17:43
-	3212	(thin adj film adj transistor) and (etch$5 with (gate near (electrode layer line conductor)))	USPAT; US-PGPUB	2004/10/13 13:10
-	1074	((thin adj film adj transistor) and (etch$5 with (gate near (electrode layer line conductor)))) and (etch$5 with (gate near (electrode layer line conductor)) with (source drain))	USPAT; US-PGPUB	2004/10/13 13:11